TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HCT573AP,TC74HCT573AF,TC74HCT573AFW

Octal D-Type Latch with 3-State Output

The TC74HCT573A is a high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Its inputs are compatible with TTL, NMOS, and CMOS output voltage levels.

Its 8-bit D-type latch is controlled by a latch enable input (LE) and a output enable input ($\overline{OE}$).

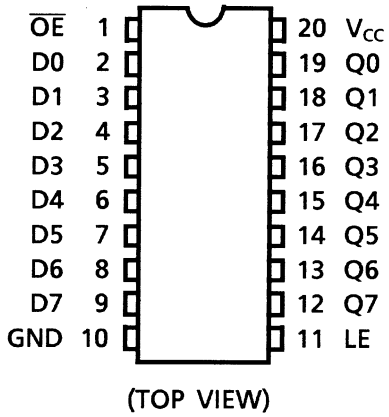
When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: t_{pd} = 18 ns (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- Compatible with TTL outputs: V_{IL} = 0.8 V (max)
  V_{IH} = 2.0 V (min)
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL}$ = 6 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74LS573

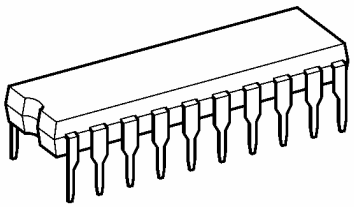
Pin Assignment



(TOP VIEW)

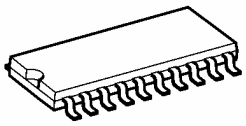
Note: xxxFW (JEDEC SOP) is not available in Japan.

TC74HCT573AP

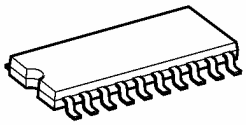


DIP20-P-300-2.54A

TC74HCT573AF

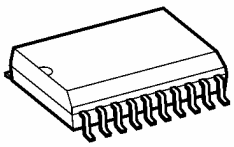


SOP20-P-300-1.27A



SOP20-P-300-1.27

TC74HCT573AFW

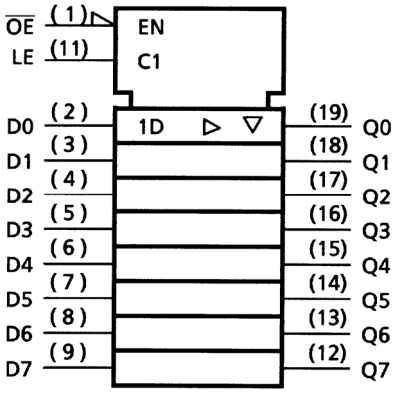


SOL20-P-300-1.27

Weight

DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)

IEC Logic Symbol



Truth Table

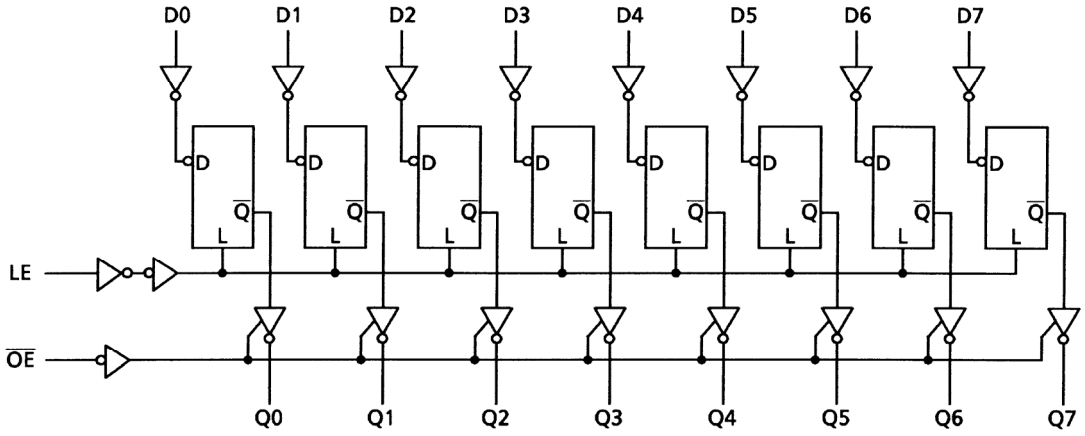
Inputs			Output
$\overline{OE}$	LE	D	Q
H	X	X	Z
L	L	X	Q_n
L	H	L	L
L	H	H	H

X: Don't care

Z: High impedance

Q_n: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7	V
DC input voltage	V_{IN}	−0.5~V_{CC} + 0.5	V
DC output voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input diode current	I_{IK}	±20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±35	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	−65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5~5.5	V
Input voltage	V_{IN}	0~V_{CC}	V
Output voltage	V_{OUT}	0~V_{CC}	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	t_r, t_f	0~500	ns

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40~85°C		Unit
			V_{CC} (V)	Min	Typ.	Max	Min	Max	
High-level input voltage	V_{IH}	—	4.5~5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V_{IL}	—	4.5~5.5	—	—	0.8	—	0.8	V
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}, I_{OH} = −20 μA	4.5	4.4	4.5	—	4.4	—	V
		V_{IN} = V_{IH} or V_{IL}, I_{OH} = −6 mA	4.5	4.18	4.31	—	4.13	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}, I_{OL} = 20 μA	4.5	—	0.0	0.1	—	0.1	V
		V_{IN} = V_{IH} or V_{IL}, I_{OL} = 6 mA	4.5	—	0.17	0.26	—	0.33	
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	5.5	—	—	±0.5	—	±5.0	μA
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND	5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND	5.5	—	—	4.0	—	40.0	μA
	I_C	Per input: V_{IN} = 0.5 V or 2.4 V Other input: V_{CC} or GND	5.5	—	—	2.0	—	2.9	mA

Timing Requirements (input: tr = tf = 6 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = −40 ~85°C	Unit
		V_{CC} (V)	Typ.	Limit		Limit	
Minimum pulse width (LE)	$t_{W(H)}$	—	4.5	—	15	19	ns
			5.5	—	14	17	
Minimum set-up time (data)	t_s	—	4.5	—	10	13	ns
			5.5	—	9	11	
Minimum hold time (data)	t_h	—	4.5	—	5	5	ns
			5.5	—	5	5	

AC Characteristics (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40~85°C		Unit
			CL (pF)	V_{CC} (V)	Min	Typ.	Max	Min	Max	
Output transition time	t_{TLH} t_{THL}	—	50	4.5	—	7	12	—	15	ns
				5.5	—	6	11	—	14	
Propagation delay time (LE-Q)	t_{pLH} t_{pHL}	—	50	4.5	—	19	29	—	36	ns
				5.5	—	17	26	—	33	
			150	4.5	—	24	37	—	46	
				5.5	—	22	34	—	43	
Propagation delay time (D-Q)	t_{pLH} t_{pHL}	—	50	4.5	—	17	26	—	33	ns
				5.5	—	14	23	—	29	
			150	4.5	—	22	34	—	43	
				5.5	—	20	31	—	39	
Output enable time	t_{pZL} t_{pZH}	R_L = 1 kΩ	50	4.5	—	18	27	—	34	ns
				5.5	—	15	24	—	30	
			150	4.5	—	23	35	—	44	
				5.5	—	20	32	—	40	
Output disable time	t_{pLZ} t_{pHZ}	R_L = 1 kΩ	50	4.5	—	18	24	—	30	ns
				5.5	—	16	22	—	28	
Input capacitance	C_{IN}	—			—	5	10	—	10	pF
Output capacitance	C_{OUT}	—			—	10	—	—	—	pF
Power dissipation capacitance	C_{PD} (Note)	—			—	38	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

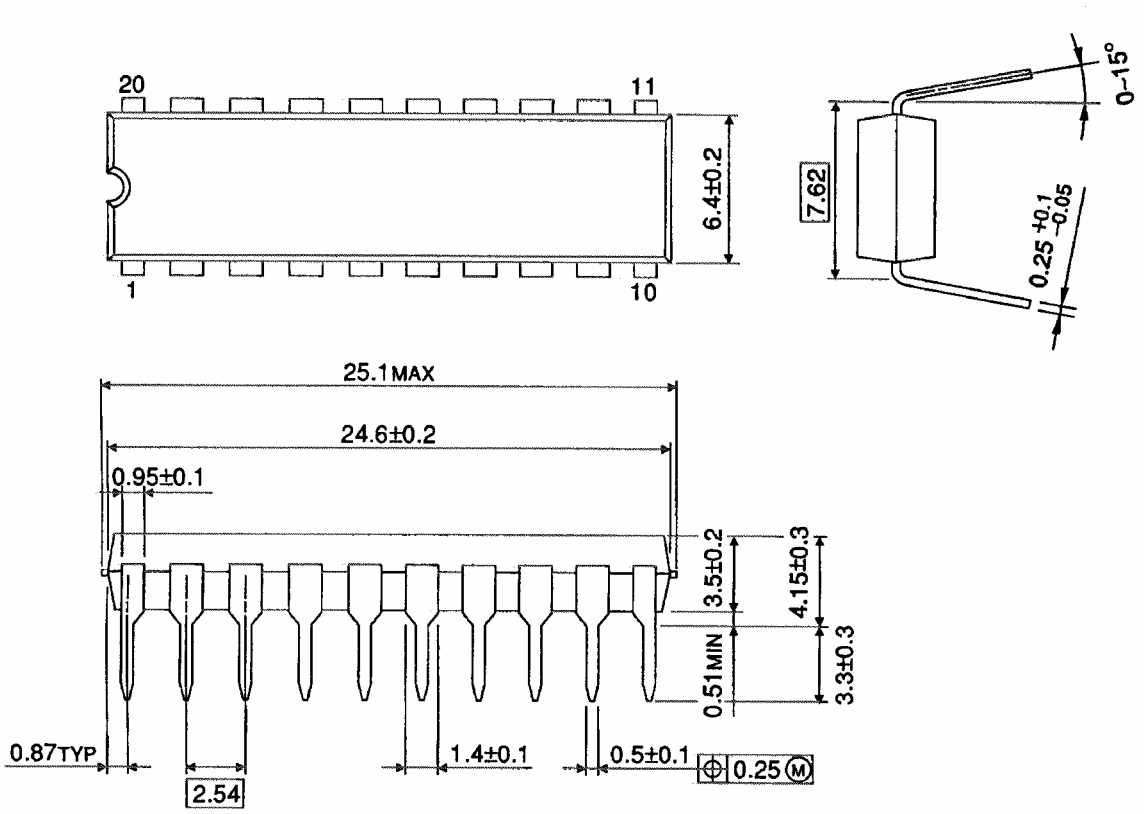
$$I_{CC}\ (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation:

$$C_{PD}\ (total) = 25 + 13 \cdot n$$

Package Dimensions

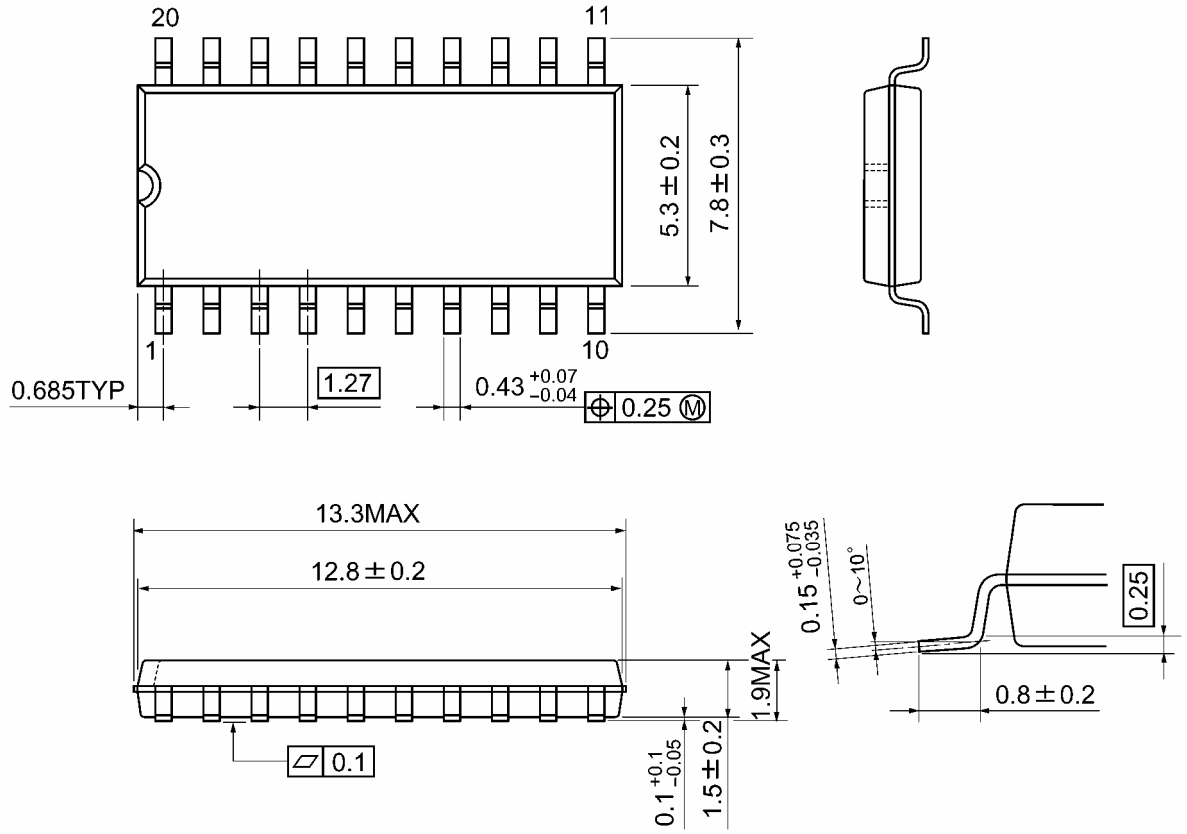
DIP20-P-300-2.54A Unit : mm



Weight: 1.30 g (typ.)

Package Dimensions

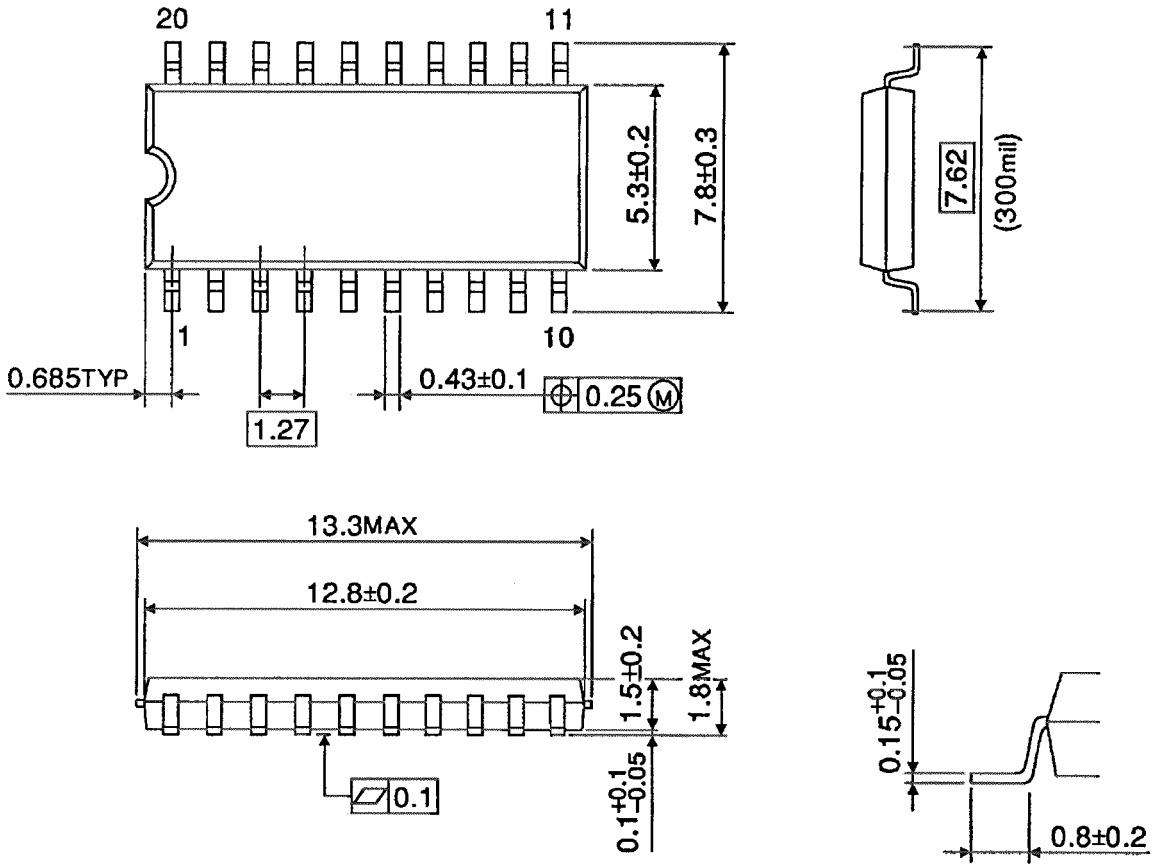
SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

Package Dimensions

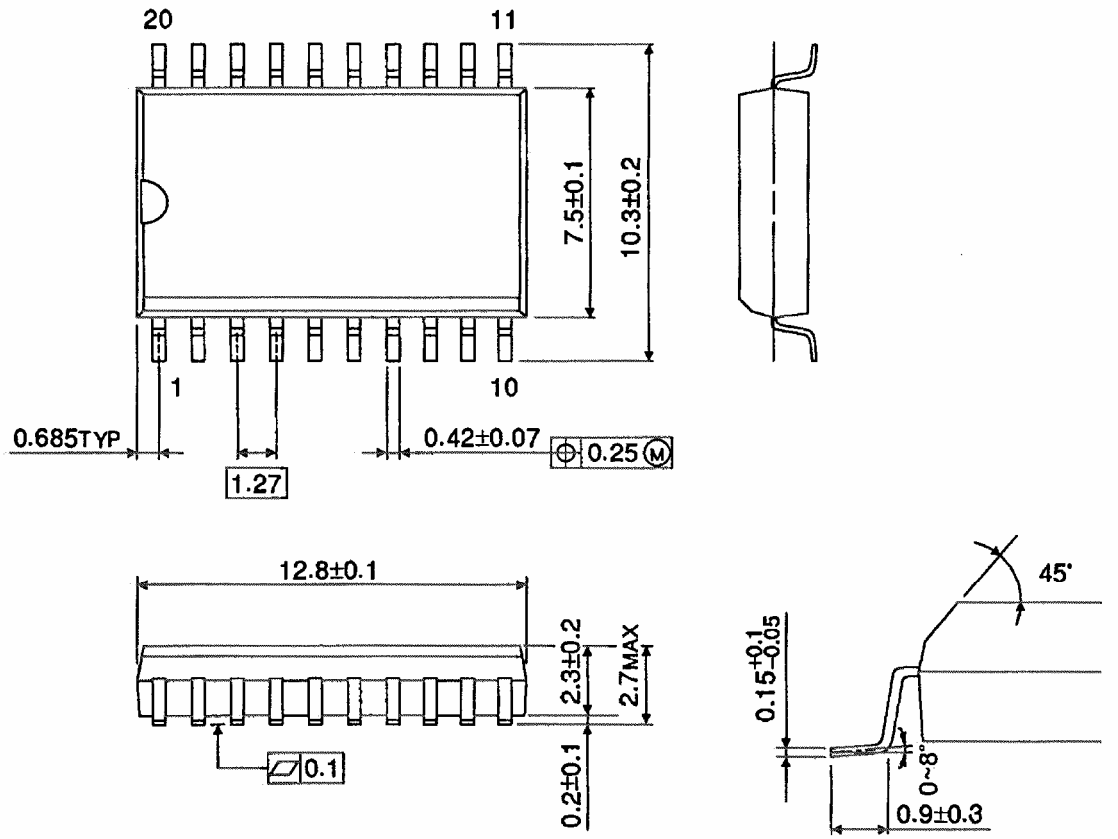
SOP20-P-300-1.27 Unit : mm



Weight: 0.22 g (typ.)

Package Dimensions (Note)

SOL20-P-300-1.27 Unit : mm



Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Note: Lead (Pb)-Free Packages

DIP20-P-300-2.54A SOP20-P-300-1.27A

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